

# 4.2V to 18V, 3A 1ch Synchronous Buck Converter integrated FET

**BD1484EFJ**

### ● General Description

The BD1484EFJ is a synchronous step-down switching regulator that integrates 2 low ON-resistance N-channel MOSFETs. It achieves 3A continuous output current over a wide input supply range. Current mode operation provides fast transient response and easy phase compensation.

## ● Features

- Low ESR Output Ceramic Capacitors are Available
- Low Standby Current during Shutdown Mode
- 380 kHz Fixed Operating Frequency
- Feedback voltage
  - $0.925V \pm 1.5\%$  ( $T_a = 25^\circ C$ ),
  - $0.925V \pm 2.0\%$  ( $T_a = -25^\circ C$  to  $85^\circ C$ )
- Protection Circuits
  - Under Voltage Lockout Protection
  - Thermal Shutdown
  - Over Current Protection

## ● Applications

- Distributed Power System
- Pre-Regulator for Linear Regulator

### ●Key Specifications

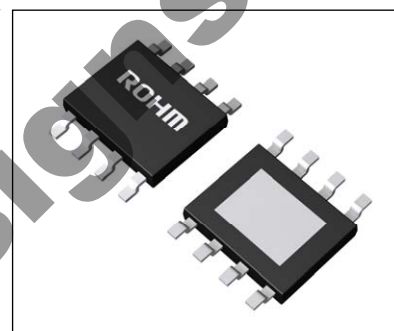
- Input voltage range: 4.2V to 18V
- Output voltage range: 0.925V to  $(V_{in} \times 0.7)V$
- Output current: 3.0A (Max.)
- Switching Frequency 380kHz(Typ.)
- Hi-side FET On-resistance:  $0.15\Omega$  (Typ.)
- Lo-side FET On-resistance:  $0.13\Omega$  (Typ.)
- Standby current: 15μA (Typ.)
- Operating temperature range: -40°C to +85°C

● **Package**

HTSOP-J8

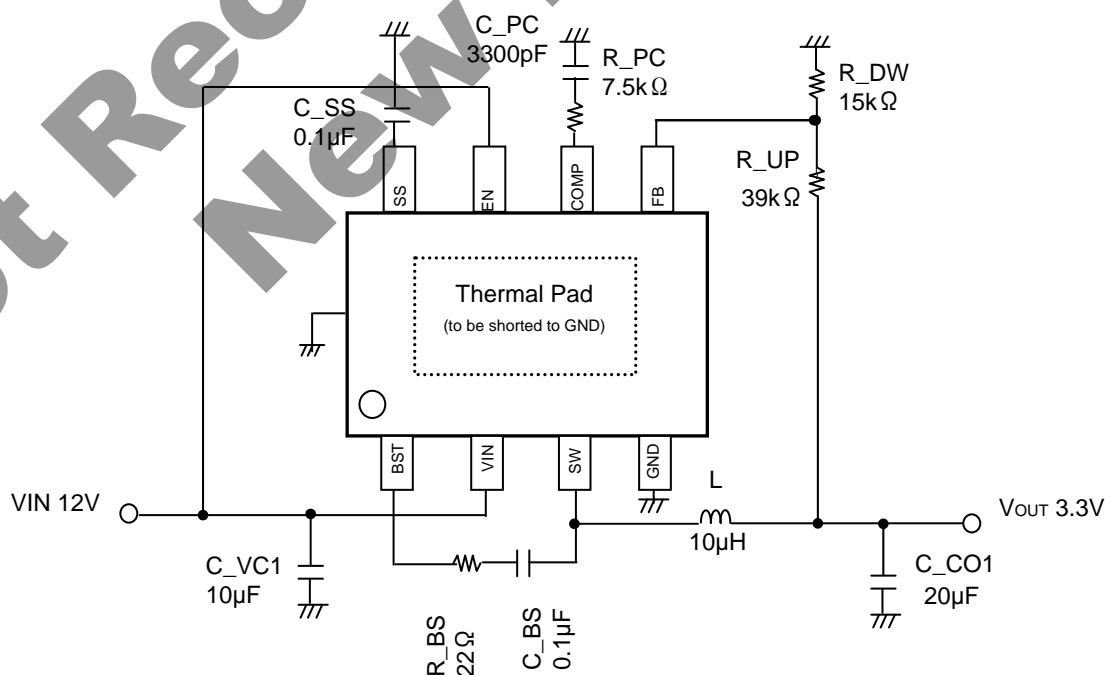
(Typ.) (Typ.) (Max.)

4.90mm x 6.00mm x 1.00mm



HTSOP-J8

### ● Typical Application Circuit



※R BS protect from VIN-BST short destruction.

Fig.1 Typical Application Circuit

Product structure : Silicon monolithic integrated circuit    This product is not designed protection against radioactive rays.

## ●Pin Configuration

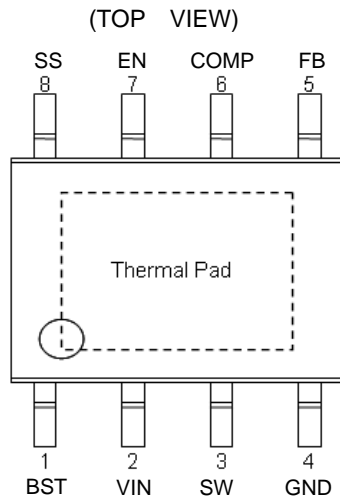


Fig.2 Pin Configuration

## ●Block Diagram

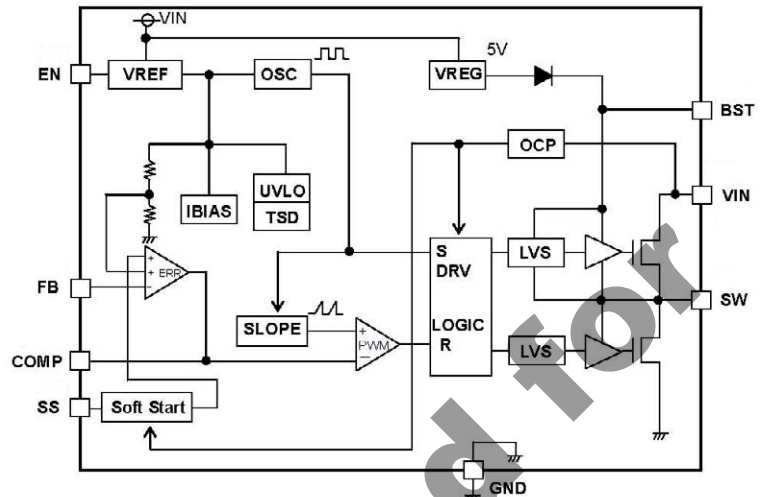


Fig.3 Block Diagram

## ●Pin Description

Pin No.	Pin name	Function
1	BST	High-Side Gate Drive Boost Input
2	VIN	Power Input
3	SW	Power Switching Output
4	GND	Ground
5	FB	Feed Back Input
6	COMP	Compensation Node
7	EN	Enable Input
8	SS	Soft Start Control Input

## ●Block Operation

- VREG  
A block to generate constant-voltage for DC/DC boosting.
- VREF  
A block that generates internal reference voltage of 5.1 V (Typ.).
- TSD/UVLO  
TSD (Thermal shutdown)/UVLO (Under Voltage Lockout) protection block.  
The TSD circuit shuts down IC at high temperature.  
The UVLO circuit shuts down the IC when the VIN is Low Voltage.
- Error amp block (ERR)  
This is the circuit to compare the reference voltage and the feedback voltage of output voltage. The COMP pin voltage resulting from this comparison determines the switching duty. At the time of startup, since the soft start is operated by the SS pin voltage, the COMP pin voltage is limited to the SS pin voltage.
- Oscillator block (OSC)  
This block generates the oscillating frequency.
- SLOPE block  
This block generates the triangular waveform from the clock created by OSC. Generated triangular waveform is sent to the PWM comparator.
- PWM block  
The COMP pin voltage output by the error amp is compared to the SLOPE block's triangular waveform to determine the switching duty. Since the switching duty is limited by the maximum duty ratio which is determined internally, it does not become 100%.
- DRV block  
A DC/DC driver block. A signal from the PWM is input to drive the power FETs.
- OCP block  
OCP (Over Current Protection) block. The current which flowed into FET is detected and OCP starts at 3.5A (min). After OCP, switching is turned off and SS capacitor is discharged. OCP is not latch type but auto restart.
- Soft start circuit  
Since the output voltage rises gradually while restricting the current at the time of startup, it is possible to prevent the output voltage overshoot or the rush current.

# ●Absolute Maximum Ratings(Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Supply Voltage	VIN	20	V
Switch Voltage	VSW	20	V
Power Dissipation for HTSOP-J8	Pd	3760 <sup>*1</sup>	mW
Package thermal resistance $\theta_{ja}$ <sup>*2</sup>	$\theta_{ja}$	29.27	°C/W
Package thermal resistance $\theta_{jc}$ <sup>*2</sup>	$\theta_{jc}$	3.75	°C/W
Operating Temperature Range	Topr	-40 to +85	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Maximum Junction Temperature	Tjmax	150	°C
BST Voltage	VBST	VSW+7	V
EN Voltage	VEN	20	V
All other pins	VOTH	20	V

\*1 Derating in done 30.08 mW/°C for operating above Ta≥25°C(Mount on 4-layer 70.0mm × 70.0mm × 1.6mm board)

\*2 Mount on 4-layer 50mm x 30mm x 1.6mm application board

# ●Operating Ratings (Ta= -40 to 85°C)

Parameter	Symbol	Ratings			Unit
		Min	Typ	Max	
Supply Voltage	VIN	4.2	12	18	V
SW Voltage	VSW	-0.5	-	18	V
Output current	ISW3	-	-	3	A
Output voltage range	V <sub>RANGE</sub>	0.925	-	VIN × 0.7	V

# ●Electrical Characteristics (Unless otherwise specified VIN=12V Ta=25°C)

Parameter	Symbol	Limits			Unit	Conditions
		Min	Typ	Max		
Error amplifier block						
FB input bias current	IFB	-	0.02	2	μA	
Feedback voltage1	VFB1	0.910	0.925	0.938	V	Voltage follower
Feedback voltage2	VFB2	0.906	0.925	0.942	V	Ta=-25°C to 85°C
SW block						
High-side FET On-resistance	RONH	-	0.15	-	Ω	ISW= -0.8A
Low-side FET On-resistance	RONL	-	0.13	-	Ω	ISW= 0.8A
High/Low-side FET Leak current	ILEAKN	-	0	10	μA	VIN= 18V, VSW = 0V / 18V
Switch Current Limit	ILIMIT3	3.5	-	-	A	
Maximum duty cycle	MDUTY	-	90	-	%	VFB= 0V
General						
Enable Sink current	IEN	45	90	135	μA	VEN= 12V
Enable Threshold voltage	VEN	0.6	1.2	1.4	V	
Under Voltage Lockout threshold	VUVLO	3.5	3.75	4.0	V	VIN rising
Under Voltage Lockout Hysteresis	VHYS	-	0.3	-	V	
Soft Start Current	ISS	5	10	15	μA	VSS= 0 V
Soft Start Time	TSS	-	22	-	ms	CSS= 0.1 μF
Operating Frequency	FOSC	300	380	460	kHz	
Circuit Current	ICC	-	1.2	3	mA	VFB= 1.5V, VEN= 12V
Standby Current	IQUI	-	15	27	μA	VEN= 0V

### ● Typical Performance Curves

(Unless otherwise specified,  $V_{IN} = 12V$   $T_a = 25^\circ C$ )

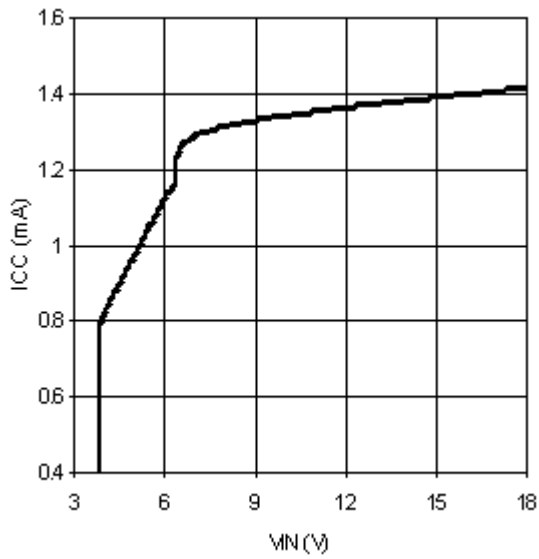


Fig.4 Circuit Current  
(No switching)

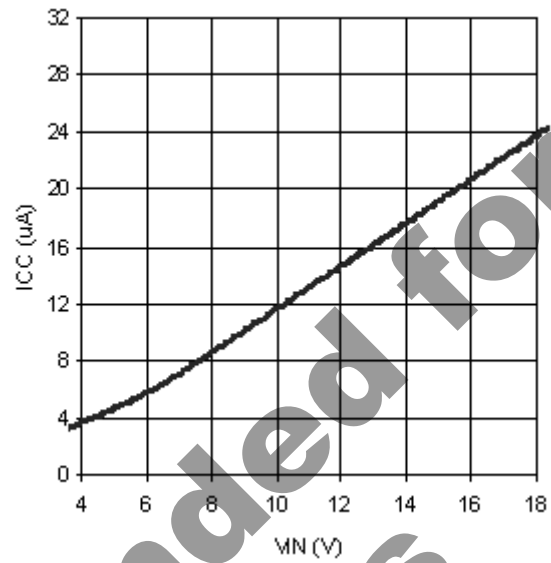


Fig.5 Stand by current  
(IC not active)

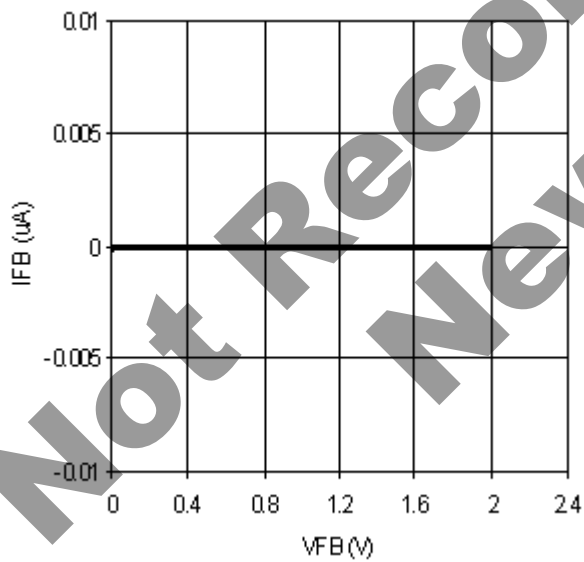


Fig.6 Input Bias Current

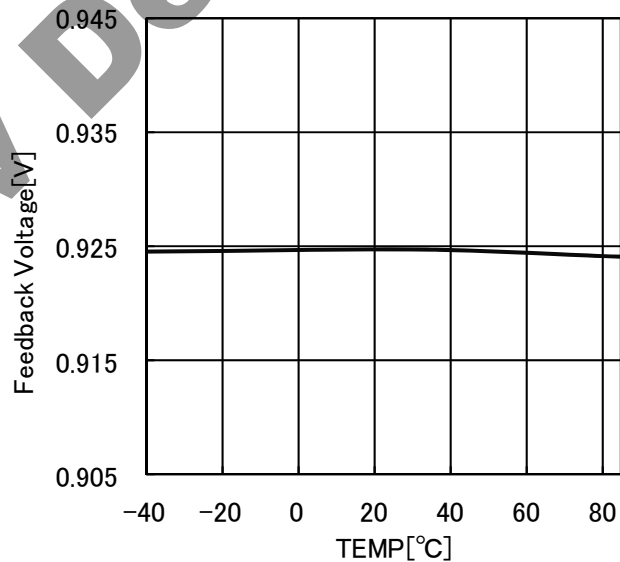


Fig.7 Feedback voltage

●Typical Performance Curves (Continued)  
(Unless otherwise specified, VIN= 12V Ta = 25°C)

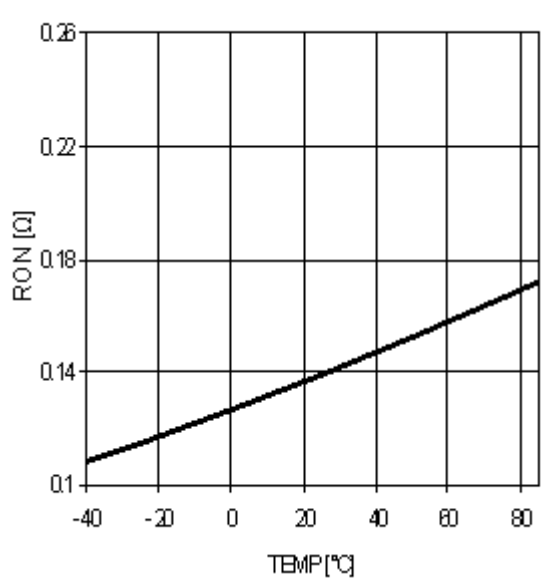


Fig.8 Hi,Low-Side  
On-resistance

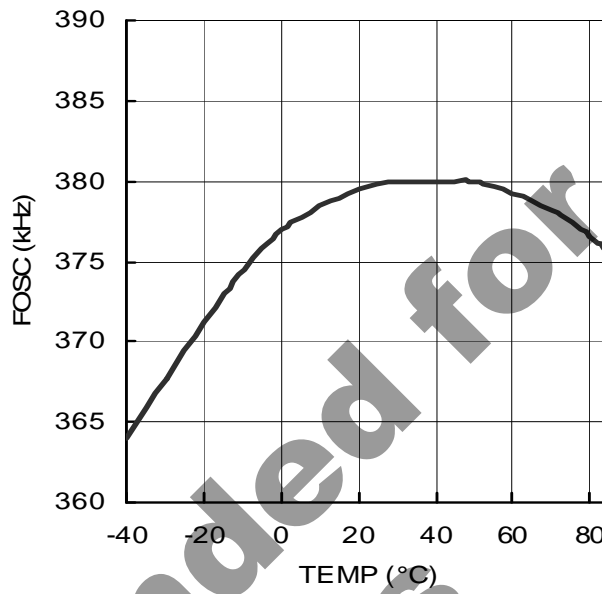


Fig.9 Operating Frequency

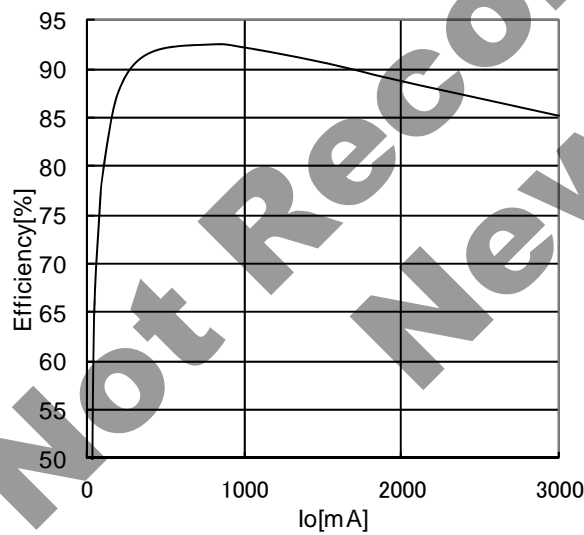


Fig.10 STEP Down Efficiency  
(VIN= 12V Vout= 3.3V L=10μH)

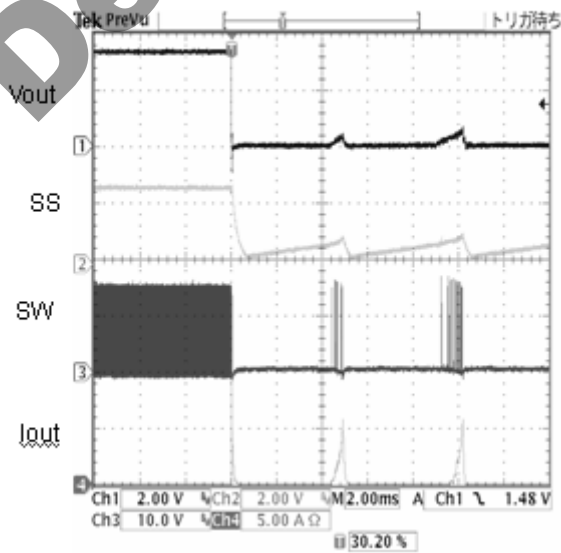


Fig.11 OverCurrent Protection  
(Vout is shorted to GND)

# ●Typical Performance Curves (Continued)

(Unless otherwise specified, VIN= 12V Ta = 25°C)

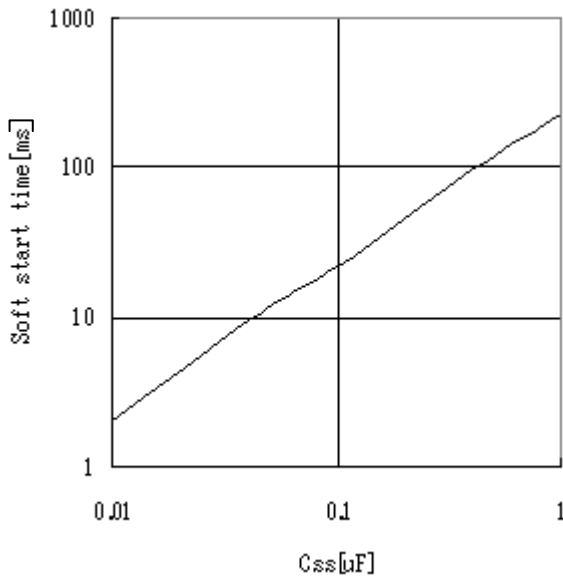


Fig.12 Soft Start Time

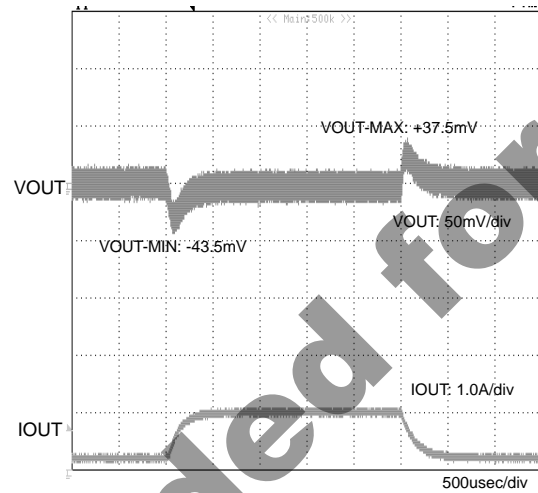


Fig.13 Transient Response  
(VIN= 12V VOUT= 3.3V L= 10μH Cout =22μF Iout= 0.2-1.0A )

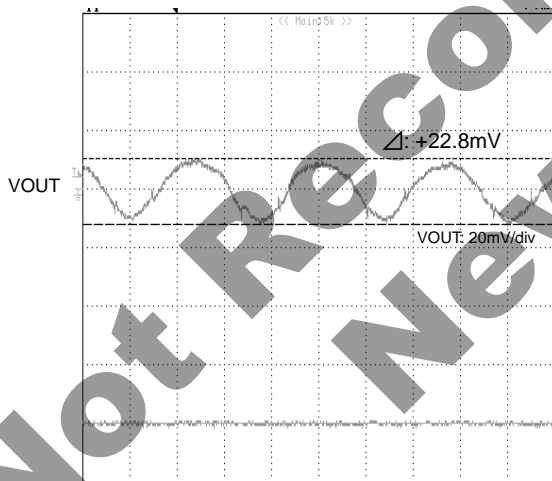


Fig.14 Output Ripple Voltage  
(VIN= 12V VOUT= 3.3V L= 10μH Cout =22μF I out= 1.0A )

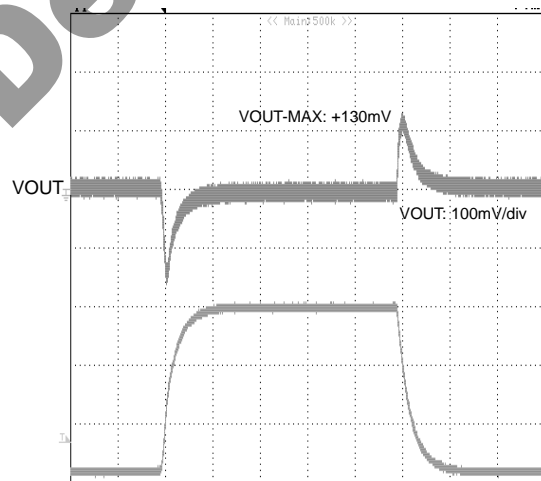


Fig.15 Transient Response  
(VIN= 12V VOUT= 3.3V L= 10μH Cout =22μF Iout= 0.2-3.0A)

### ●Typical Performance Curves (Continued)

(Unless otherwise specified,  $V_{IN} = 12V$   $T_a = 25^\circ C$ )

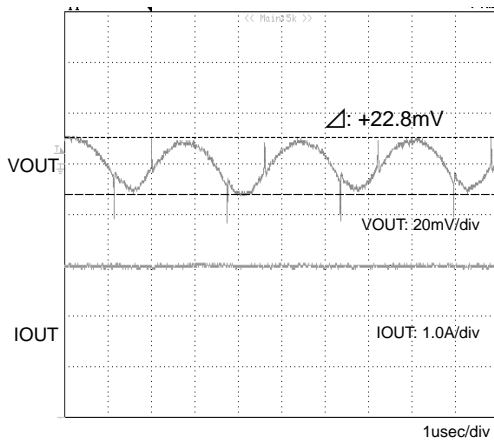


Fig.16 Output Ripple Voltage  
( $V_{IN} = 12V$   $V_{OUT} = 3.3V$   $L = 10\mu H$   $C_{out} = 22\mu F$   $I_{out} = 3.0A$ )

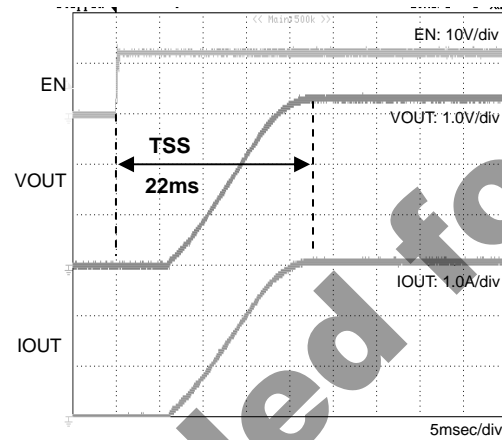


Fig.17 Start Up waveform  
( $V_{IN} = 12V$   $V_{OUT} = 3.3V$   $L = 10\mu H$   $C_{SS} = 0.1\mu F$ )

●Application Information  
Typical Application Circuit

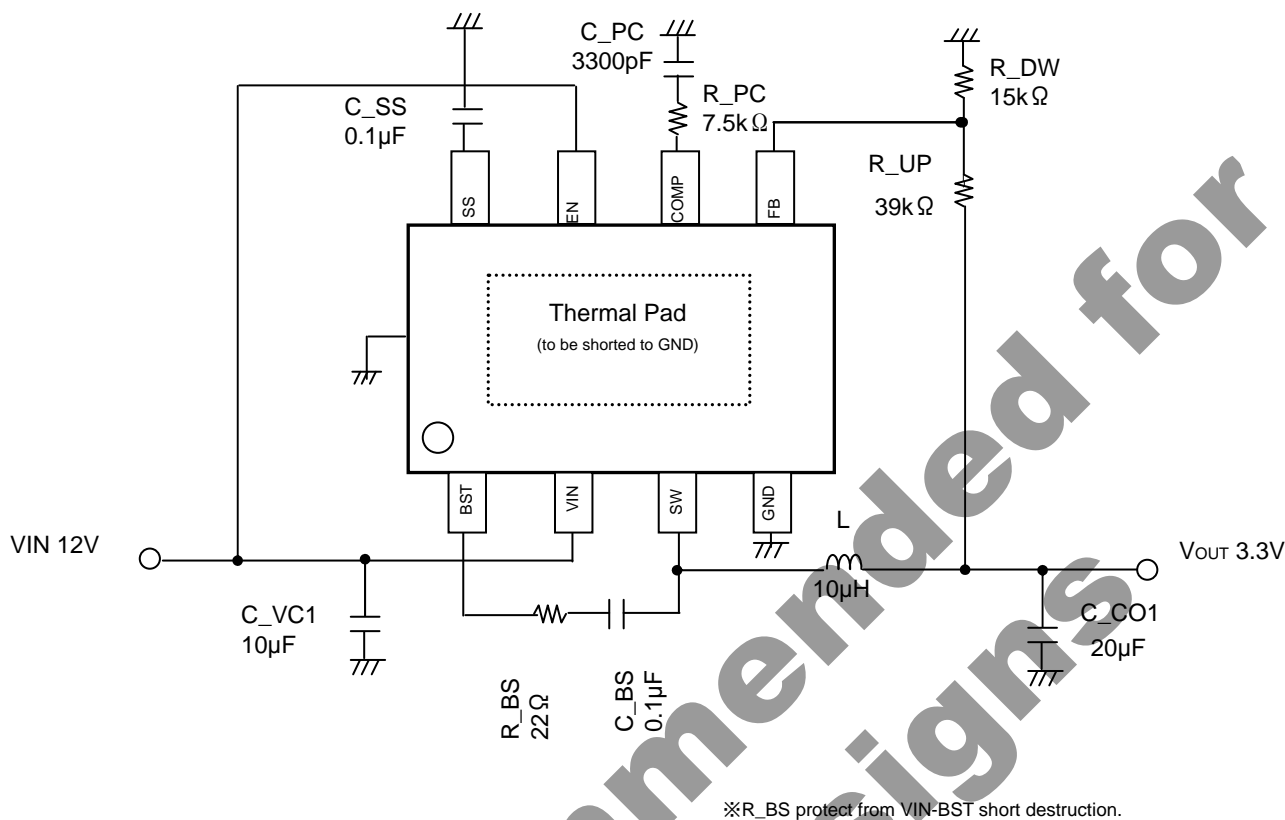


Fig.18 Application Circuit

	Symbol	Maker	Part No	
Input capacitor	C_VC1	TDK	C3225JB1E106K	10µF/25V
Output capacitor	C_CO1	TDK	C3216JB1C106M	10µF/16V
Inductor	L	TDK	SLF10165-100M3R8	10µH/3.8A



### Selecting Application Components

#### (1) Output LC filter constant selection (Buck Converter)

The Output LC filter is required to supply constant current to the output load. A larger value inductance at this filter results in less inductor ripple current ( $\Delta I_L$ ) and less output ripple voltage. However, the larger value inductors tend to have less fast load transient-response, a larger physical size, a lower saturation current and higher series resistance. A smaller value inductance has almost opposite characteristics above. So Choosing the Inductor ripple current ( $\Delta I_L$ ) between 20 to 40% of the averaged inductor current (equivalent to the output load current) is a good compromise.

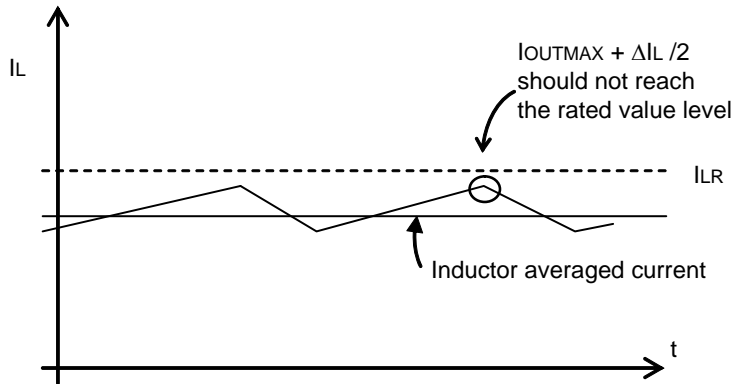


Fig.19

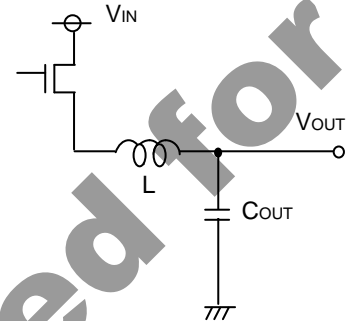


Fig.20

Setting  $\Delta I_L = 30\% \times \text{Averaged Inductor current (2A)} = 0.6 \text{ [A]}$

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT}) \times 1}{V_{IN} \times F_{OSC} \times \Delta I_L} = 10 \mu \text{ [H]}$$

Where  $V_{IN} = 12\text{V}$ ,  $V_{OUT} = 3.3\text{V}$ ,  $F_{OSC} = 380 \text{ kHz}$ ,  
;  $F_{OSC}$  is a switching frequency

Also the inductor should have the higher saturation current than  $I_{OUTMAX} + \Delta I_L / 2$ .

The output capacitor  $C_{OUT}$  affects the output ripple-voltage. Choose the large capacitor to achieve the small ripple-voltage enough to meet the application requirement.

Output ripple voltage  $\Delta V_{RPL}$  is calculated by the following equation.

$$\Delta V_{RPL} = \Delta I_L \times \left( R_{ESR} + \frac{1}{8 \times C_{OUT} \times F_{OSC}} \right) \text{ [V]}$$

Where  $R_{ESR}$  is a parasitic series resistance in output capacitor.

Setting  $C_{OUT} = 20 \mu\text{F}$ ,  $R_{ESR} = 10 \text{ m}\Omega$

$$\Delta V_{RPL} = 0.6 \times \left( 10 \text{ m} + \frac{1}{8 \times 20 \mu \times 380 \text{ k}} \right) = 15.8 \text{ mV}$$

#### (2) Loop Compensation

Choosing compensation capacitor  $C_{CMP}$  and resistor  $R_{CMP}$

The current-mode buck converter has 2-poles and 1-zero system. Choosing the compensation resistor and capacitor is important for a good load-transient response and good stability.

The example of DC/DC converter application bode plot is shown below.

The compensation resistor  $R_{CMP}$  will decides the cross over frequency  $F_{CRS}$  (the frequency that the total DC-DC loop-gain falls to 0dB).

Setting the higher cross over frequency achieves good response speed, however less stability. While setting the lower cross over frequency shows good stability but worse response speed.

The 1/10 of switching frequency for the cross over frequency shows a good performance at most applications.

(i) Choosing phase compensation resistor  $R_{CMP}$ 

The compensation resistor  $R_{CMP}$  can be on following formula.

$$R_{CMP} = \frac{2\pi \times V_{OUT} \times F_{CRS} \times C_{OUT}}{V_{FB} \times G_{MP} \times G_{MA}} \quad [\Omega]$$

Where

$V_{OUT}$  ; Output voltage,  $F_{CRS}$  ; Cross over frequency,  $C_{OUT}$  ; Output Capacitor,  
 $V_{FB}$  ; internal feedback voltage (**0.925V(TYP)**),  $G_{MP}$  ; Current Sense Gain (**7.8A/V(TYP)**),  
 $G_{MA}$  ; Error Amplifier Trans-conductance (**300 $\mu$ A/V(TYP)**)

Setting  $V_{OUT}= 3.3V$ ,  $F_{CRS}= 38kHz$ ,  $C_{OUT}= 20\mu F$ ;

$$R_{CMP} = \frac{2\pi \times 3.3 \times 38k \times 20u}{0.925 \times 7.8 \times 300u} = 7.29k \sim 7.5k \quad [\Omega]$$

(ii) Choosing phase compensation capacitor  $C_{CMP}$ 

For the stability of DC/DC converter, canceling the phase delay that derives from output capacitor  $C_{OUT}$  and resistive load  $R_{OUT}$  by inserting the phase advance.

The phase advance can be added by the zero on compensation resistor  $R_{CMP}$  and capacitor  $C_{CMP}$ .

Making  $F_z = F_{CRS} / 6$  gives a first-order estimate of  $C_{CMP}$ .

$$\text{Compensation Capacitor} \quad C_{CMP} = \frac{1}{2\pi \times R_{CMP} \times F_z} \quad [F]$$

Setting  $F_z = F_{CRS}/6 = 6.3kHz$ ;

$$\text{Compensation Capacitor} \quad C_{CMP} = \frac{1}{2\pi \times 7.5k \times 6.3k} = 3.54n \sim 3.3n \quad [F]$$

However, the best values of zero and  $F_{CRS}$  are different between applications. After calculation above formula and confirmation actual application, please decide values finally.

## (iii) The condition of the loop compensation stability

The stability of DC/DC converter is important. To secure the operating stability, please check the loop compensation has the enough phase-margin. For the condition of loop compensation stability, the phase-delay must be less than 150 degree where Gain is 0 dB.

Feed forward capacitor  $C_{RUP}$  boosts phase margin over a limited frequency range and is sometimes used to improve loop response.  $C_{RUP}$  will be more effective if  $R_{UP} \gg R_{UP} || R_{DW}$

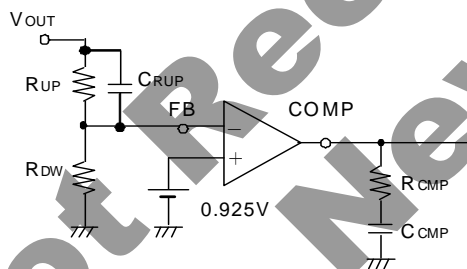


Fig.21

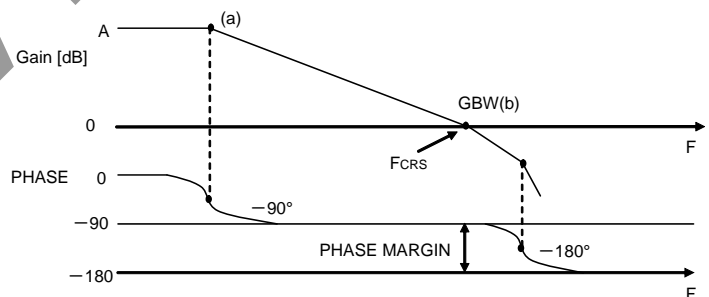


Fig.22

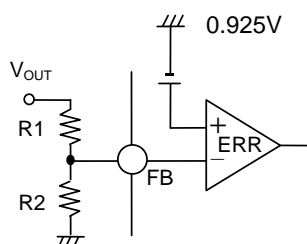
(3) Design of Feedback Resistance constant  
Set the feedback resistance as shown below.

Fig.23

$$V_{OUT} = \frac{R1 + R2}{R2} \times 0.925 \quad [V]$$

## Soft Start Function

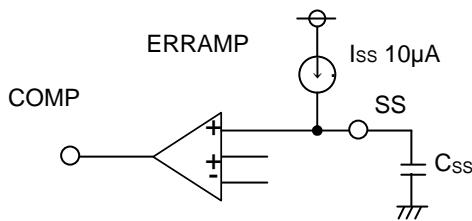


Fig.24

An adjustable soft-start function to prevent high inrush current during start-up is available. The soft-start time is set by the external capacitor connected to SS pin.

The soft start time is given by;

$$T_{ss} [s] = 2.2 \times C_{ss} / I_{ss}$$

Setting  $C_{ss} = 0.1\mu F$ ;

$$T_{ss} = 2.2 \times 0.1\mu / 10\mu = 22 [ms]$$

Please confirm the overshoot of the output voltage and inrush current when deciding the SS capacitor value.

## EN Function

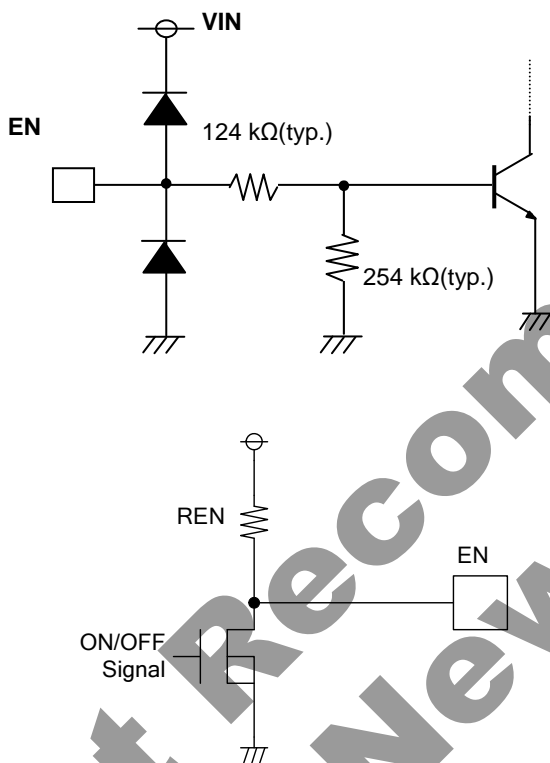


Fig.25

The EN terminal control IC's shut down.

Leaving EN terminal open makes IC shutdown.

To start the IC, EN terminal should be connected to VIN or the other power source output.

When the EN voltage exceed 1.2V (typ.), the IC start operating.

The IC also has the hysteresis voltage 0.2V (typ.) of EN when EN voltage falls down.

## (Attention1)

Chattering happens if standing lowering speed is slow when standing of EN pin is lowered.

The reverse current in which the input side and the pressure operation are done from the output side is generated when chattering operates with the output voltage remained, and there is a case to destruction.

Please set to stand within 100us when you control ON/OFF by the EN signal.

This necessity doesn't exist when EN pin is connected with VIN and EN is not controlled.

The control by open drain MOSFET shown in a left chart is recommended.

## (Attention 2)

In case the output voltage is used in a setting of more than 5V, when EN signal is turned off, please start up EN again after output voltage is discharged enough.

If EN is turned on although output voltage isn't discharged enough, BST circuit doesn't operate normally.

As the result, the IC is not operated, in the worst case, it is destroyed.

### Layout Pattern Consideration

Two high pulsing current flowing loops exist in the buck regulator system. The first loop, when FET is ON, starts from the input capacitors, to the VIN terminal, to the SW terminal, to the inductor, to the output capacitors, and then returns to the input capacitor through GND. The second loop, when FET is OFF, starts from the low FET, to the inductor, to the output capacitor, and then returns to the low FET through GND. To reduce the noise and improve the efficiency, please minimize these two loop area. Especially input capacitor, output capacitor and low FET should be connected to GND plain. PCB Layout may affect the thermal performance, noise and efficiency greatly. So please take extra care when designing PCB Layout patterns.

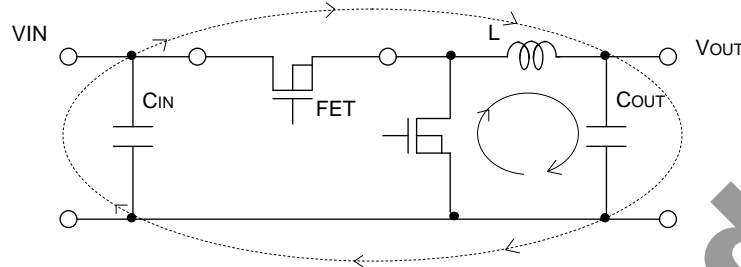


Fig.26 Current loop in Buck regulator system

- The thermal Pad on the back side of IC has the great thermal conduction to the chip. So using the GND plain as broad and wide as possible can help thermal dissipation. And a lot of thermal via for helping the spread of heat to the different layer is also effective.
- The input capacitors should be connected as close as possible to the VIN terminal.
- When there is unused area on PCB, please arrange the copper foil plain of DC nodes, such as GND, VIN and VOUT for helping heat dissipation of IC or circumference parts.
- To avoid the noise influence from AC combination with the other line, keep the switching line such as SW not extend as much as possible, and trace shortly and thickly to coil.
- Keep sensitive signal traces such as trace connected FB and COMP away from SW pin.
- The inductor and the output capacitors should be placed close to SW pin as much as possible.

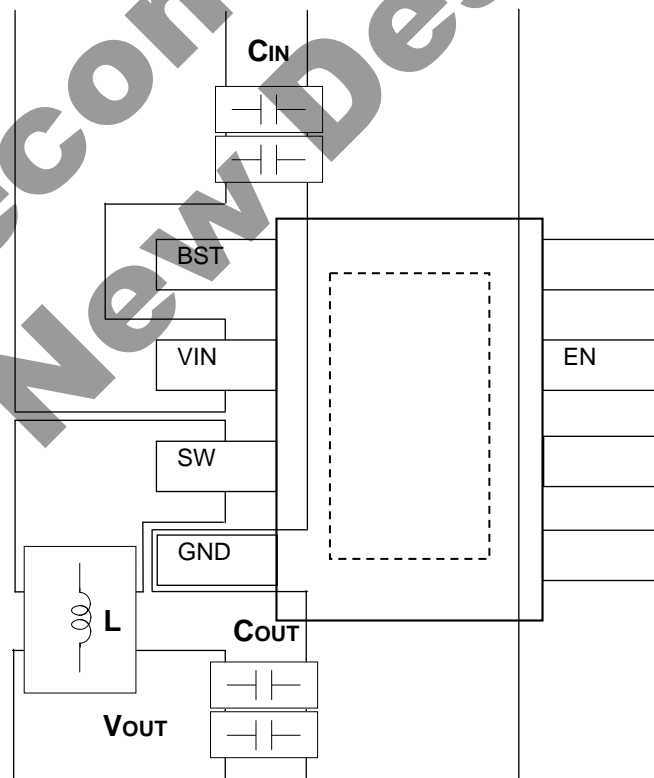


Fig.27 The example of PCB layout pattern

I/O Equivalent Circuit Diagram

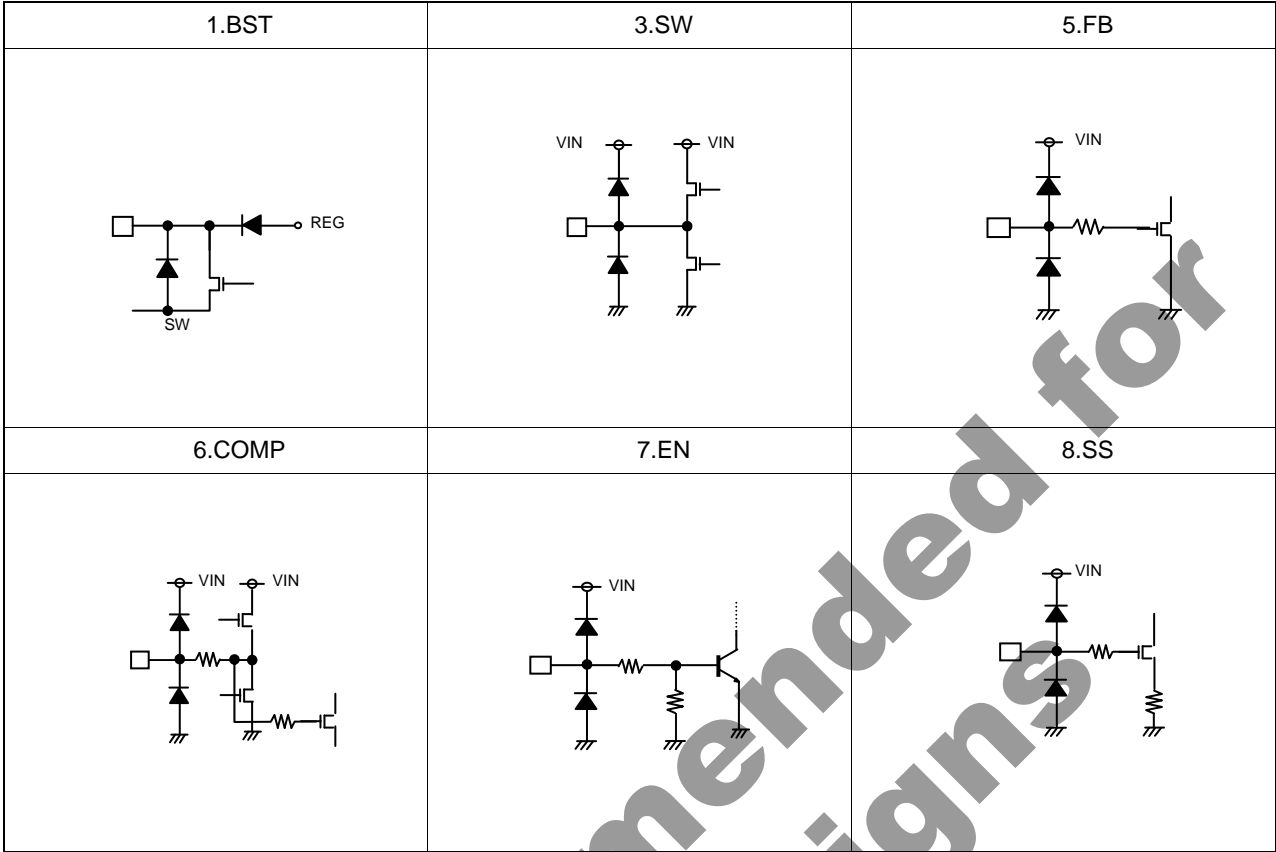
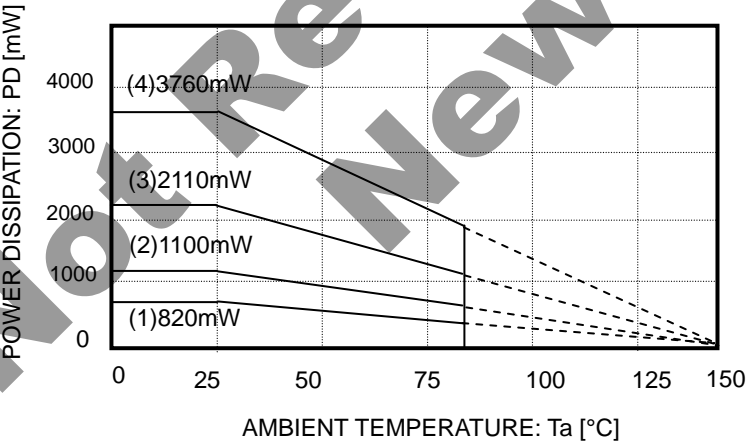


Fig.28 I/O Equivalent Circuit

Power Dissipation



**HTSOP-J8 Package**  
On 70 × 70 × 1.6 mm glass epoxy PCB  
(1) 1-layer board (Backside copper foil area 0 mm × 0 mm)  
(2) 2-layer board (Backside copper foil area 15 mm × 15 mm)  
(3) 2-layer board (Backside copper foil area 70 mm × 70 mm)  
(4) 4-layer board (Backside copper foil area 70 mm × 70 mm)

## ●Operational Notes

- 1) Absolute maximum ratings  
Use of the IC in excess of absolute maximum ratings such as the applied voltage or operating temperature range may result in IC damage. Assumptions should not be made regarding the state of the IC (short mode or open mode) when such damage is suffered. A physical safety measure such as a fuse should be implemented when use of the IC in a special mode where the absolute maximum ratings may be exceeded is anticipated.
- 2) GND potential  
Ensure a minimum GND pin potential in all operating conditions.
- 3) Setting of heat  
Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.
- 4) Pin short and mistake fitting  
Use caution when orienting and positioning the IC for mounting on printed circuit boards. Improper mounting may result in damage to the IC. Shorts between output pins or between output pins and the power supply and GND pins caused by the presence of a foreign object may result in damage to the IC.
- 5) Actions in strong magnetic field  
Use caution when using the IC in the presence of a strong magnetic field as doing so may cause the IC to malfunction.
- 6) Testing on application boards  
When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Ground the IC during assembly steps as an antistatic measure, and use similar caution when transporting or storing the IC. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process.
- 7) Ground wiring patterns  
When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the application's reference point so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring patterns of any external components.
- 8) Regarding input pin of the IC  
This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P/N junctions are formed at the intersection of these P layers with the N layers of other elements to create a variety of parasitic elements.  
For example, when the resistors and transistors are connected to the pins as shown in Fig.29, a parasitic diode or a transistor operates by inverting the pin voltage and GND voltage.  
The formation of parasitic elements as a result of the relationships of the potentials of different pins is an inevitable result of the IC's architecture. The operation of parasitic elements can cause interference with circuit operation as well as IC malfunction and damage. For these reasons, it is necessary to use caution so that the IC is not used in a way that will trigger the operation of parasitic elements such as by the application of voltages lower than the GND (P substrate) voltage to input and output pins.

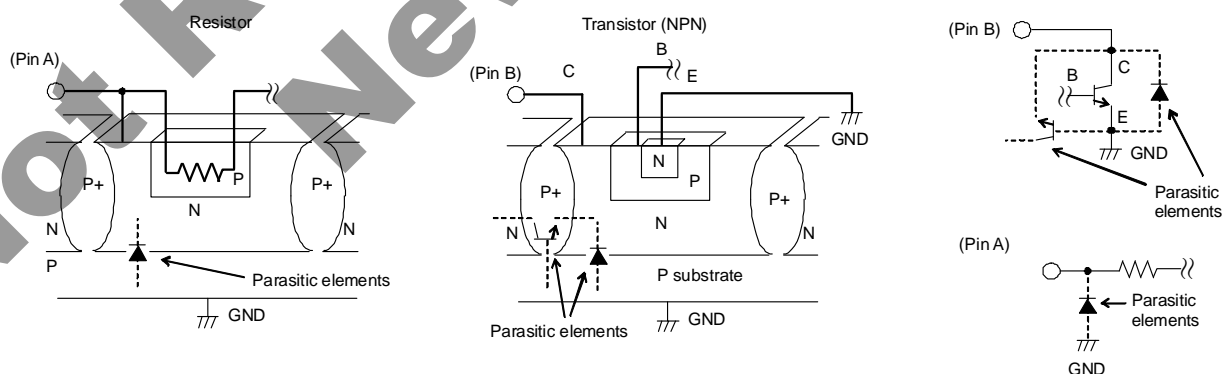


Fig.29 Example of a Simple Monolithic IC Architecture

- 9) Overcurrent protection circuits  
An overcurrent protection circuit designed according to the output current is incorporated for the prevention of IC damage that may result in the event of load shorting. This protection circuit is effective in preventing damage due to sudden and unexpected accidents. However, the IC should not be used in applications characterized by the continuous operation or transitioning of the protection circuits. At the time of thermal designing, keep in mind that the current capacity has negative characteristics to temperatures.

## 10) Thermal shutdown circuit (TSD)

This IC incorporates a built-in TSD circuit for the protection from thermal destruction. The IC should be used within the specified power dissipation range. However, in the event that the IC continues to be operated in excess of its power dissipation limits, the attendant rise in the chip's junction temperature  $T_j$  will trigger the TSD circuit to turn off all output power elements. Operation of the TSD circuit presumes that the IC's absolute maximum ratings have been exceeded. Application designs should never make use of the TSD circuit.

## 11) EN control speed

Chattering happens if standing lowering speed is slow when standing of EN pin is lowered. The reverse current in which the input side and the pressure operation are done from the output side is generated when chattering operates with the output voltage remained, and there is a case to destruction. Please set to stand within 100 $\mu$ s when you control ON/OFF by the EN signal.

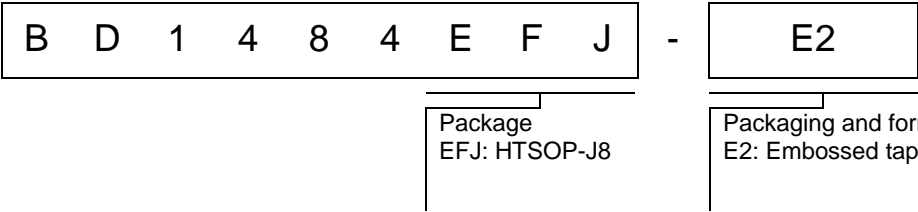
Not Recommended for  
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## Status of this document

The Japanese version of this document is formal specification. A customer may use this translation version only for a reference to help reading the formal version.

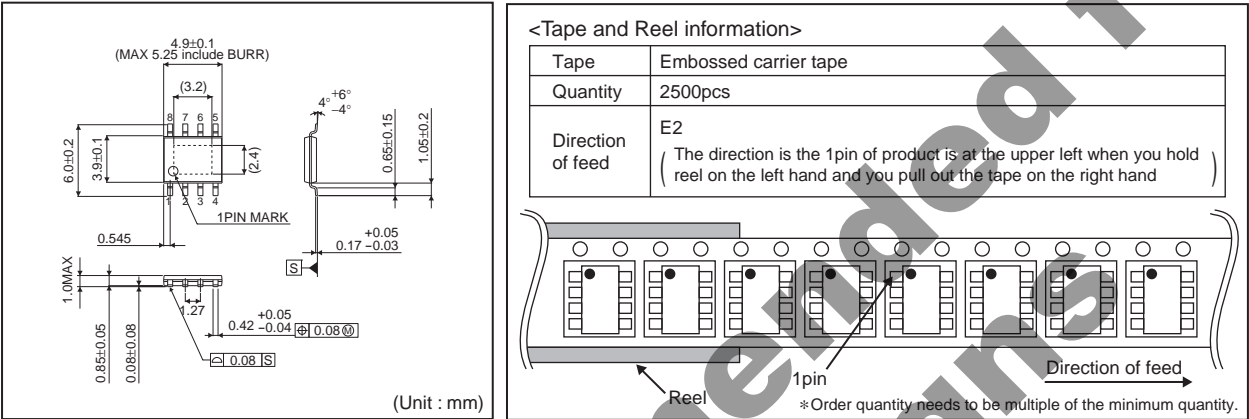
If there are any differences in translation version of this document formal version takes priority.

●Ordering Information

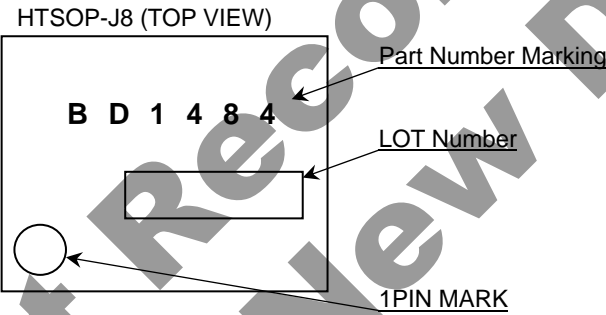


●Physical Dimension Tape and Reel Information

HTSOP-J8



●Marking Diagram





●Revision History

Date	Revision	Changes
06.Aug.2012	001	New Release

Not Recommended for  
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# Notice

## Precaution on using ROHM Products

- Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment <sup>(Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASS III	CLASS III	CLASS II b	CLASS III
CLASS IV		CLASS III	

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  - Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - Sealing or coating our Products with resin or other coating materials
  - Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - Use of the Products in places subject to dew condensation
- The Products are not subject to radiation-proof design.
- Please verify and confirm characteristics of the final or mounted products in using the Products.
- In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

## Precaution for Mounting / Circuit board design

- When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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## Precaution for Electrostatic

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1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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## Precaution for Disposition

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